SGS-THOMSON MICROELECTRONICS

L200

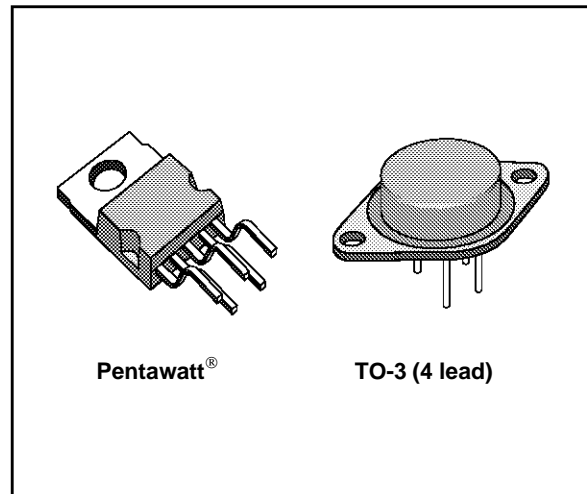# ADJUSTABLE VOLTAGE AND CURRENT REGULATOR

- ADJUSTABLE OUTPUT CURRENT UP TO 2 A (GUARANTEED UP TO T_j = 150 °C)
- ADJUSTABLE OUTPUT VOLTAGE DOWN TO 2.85 V
- INPUT OVERVOLTAGE PROTECTION (UP TO 60 V, 10 ms)
- SHORT CIRCUIT PROTECTION
- OUTPUT TRANSISTOR S.O.A. PROTECTION
- THERMAL OVERLOAD PROTECTION
- LOW BIAS CURRENT ON REGULATION PIN
- LOW STANDBY CURRENT DRAIN

Pentawatt®   **TO-3 (4 lead)**

DESCRIPTION

The L200 is a monolithic integrated circuit for voltage and current programmable regulation. It is available in Pentawatt® package or 4-lead TO-3 metal case. Current limiting, power limiting, thermal shutdown and input overvoltage protection (up to 60 V) make the L200 virtually blow-out proof.

The L200 can be used to replace fixed voltage regulators when high output voltage precision is required and eliminates the need to stock a range of fixed voltage regulators.

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_i	DC Input Voltage	40	V
V_i	Peak Input Voltage (10 ms)	60	V
ΔV_{i-o}	Dropout Voltage	32	V
I_o	Output Current	internally limited	
P_{tot}	Power Dissipation	internally limited	
T_{stg}	Storage Temperature	-55 to 150	°C
T_{op}	Operating Junction Temperature for L200C	-25 to 150	°C
	for L200	-55 to 150	°C

THERMAL DATA

			TO-3	Pentawatt®
$R_{th\ j-case}$	Thermal Resistance Junction-case	Max	4 °C/W	3 °C/W
$R_{th\ j-amb}$	Thermal Resistance Junction-ambient	Max	35 °C/W	50 °C/W

CONNECTION DIAGRAMS AND ORDER CODES (top views)
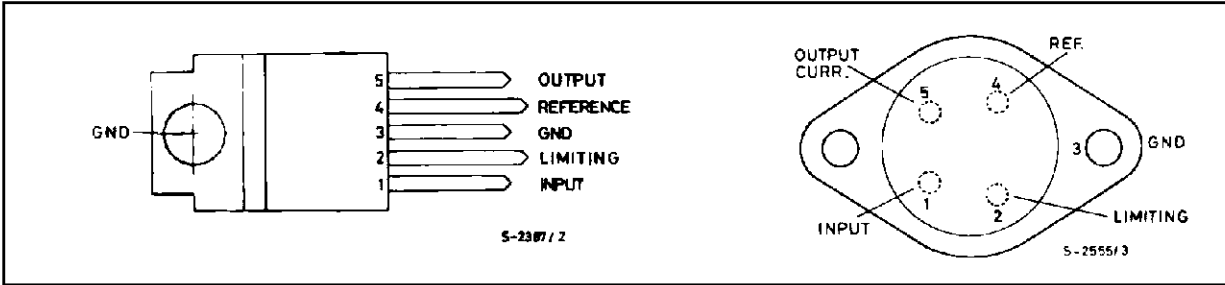
Type	Pentawatt®	TO-3
L200		L200 T
L200 C	L200 CH L200 CV	L200 CT

BLOCK DIAGRAM
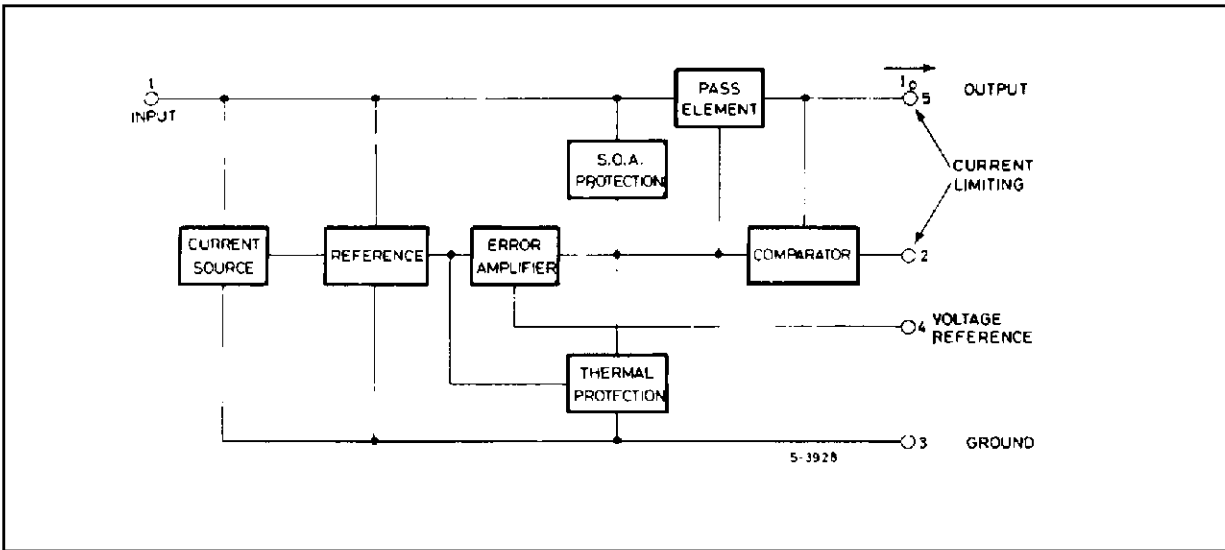
APPLICATION CIRCUITS

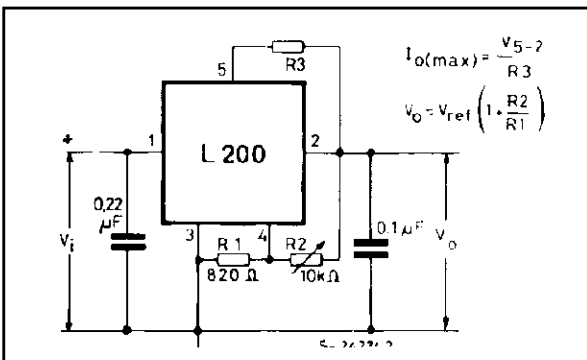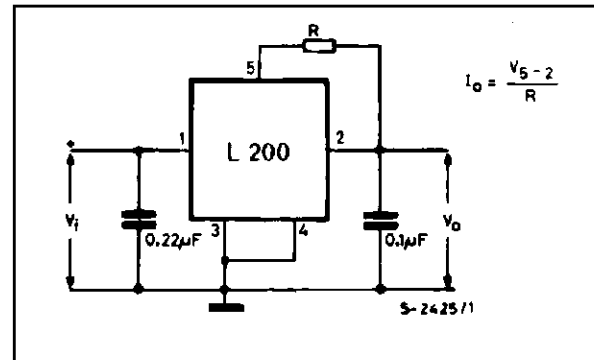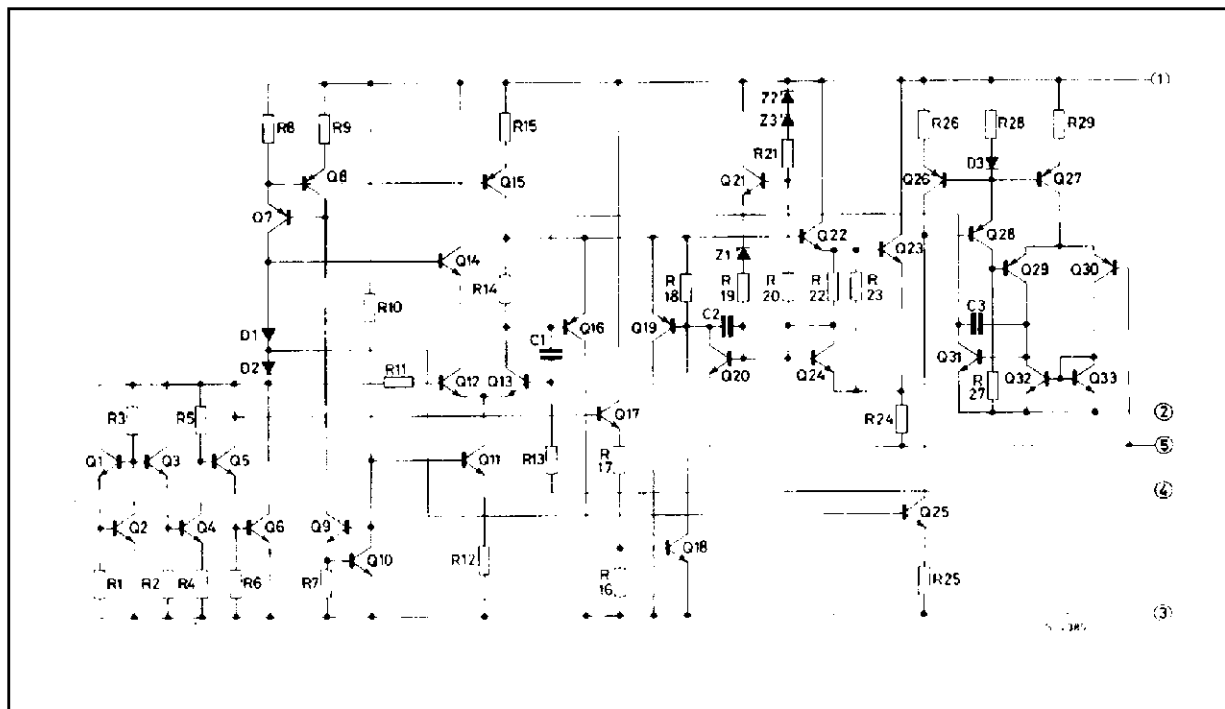**Figure 1. Programmable Voltage Regulator with Current Limiting**

$$I_{o(max)} = \frac{V_{5-2}}{R3}$$

$$V_o = V_{ref}\left(1 + \frac{R2}{R1}\right)$$

Figure 2. Programmable Current Regulator.

$$I_o = \frac{V_{5-2}}{R}$$

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SCHEMATIC DIAGRAM

ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit

VOLTAGE REGULATION LOOP

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_d	Quiescent drain Current (pin 3)	V_i = 20 V		4.2	9.2	mA
e_N	Output Noise Voltage	V_o = Vref I_o = 10 mA B = 1 MHz		80		μV
V_o	Output Voltage Range	I_o = 10 mA	2.85		36	V
$\dfrac{\Delta V_o}{V_o}$	Voltage Load Regulation (note 1)	ΔI_o = 2 A ΔI_o = 1.5 A		0.15 0.1	1 0.9	% %
$\dfrac{\Delta V_i}{\Delta V_o}$	Line Regulation	V_0 = 5 V V_i = 8 to 18 V	48	60		dB
SVR	Supply Voltage Rejection	V_0 = 5 V I_o = 500 mA ΔV_i = 10 V_{pp} f = 100 Hz (note 2)	48	60		dB
ΔV_{i-o}	Droupout Voltage between Pins 1 and 5	I_o = 1.5 A $\Delta V_0 \leq 2\%$		2	2.5	V
V_{ref}	Reference Voltage (pin 4)	V_i = 20 V I_o = 10 mA	2.64	2.77	2.86	V

ELECTRICAL CHARACTERISTICS (continued)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
ΔV_{ref}	Average Temperature Coefficient of Reference Voltage	$V_i = 20$ V Io = 10mA for Tj = - 25 to 125 °C for Tj = 125 to 150 °C		-0.25 -1.5		mV/°C mV/°C
I_4	Bias Current and Pin 4			3	10	μA
$\dfrac{\Delta I_4}{\Delta T \bullet I_4}$	Average Temperature Coefficient (pin 4)			-0.5		%/°C
Z_o	Output Impedance	$V_i = 10$ V $V_o = V_{ref}$ $I_o = 0.5$ A $f = 100$ Hz		1.5		mΩ

CURRENT REGULATION LOOP

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
V_{SC}	Current Limit Sense Voltage between Pins 5 and 2	$V_i = 10$ V $V_o = V_{ref}$ $I_5 = 100$ mA	0.38	0.45	0.52	V
$\dfrac{\Delta V_{SC}}{\Delta T \bullet V_{SC}}$	Average Temperature Coefficient of V_{SC}			0.03		%/°C
$\dfrac{\Delta I_o}{I_o}$	Current Load Regulation	Vi = 10 V $\Delta Vo = 3V$ $I_o = 0.5$ A $I_o = 1A$ $I_o = 1.5$ A		1.4 1 0.9		% % %
I_{SC}	Peak Short Circuit Current	$V_i - V_0 = 14$ V (pins 2 and 5 short circuited)			3.6	A

Note 1: A load step of 2 A can be applied provited that input-output differential voltage is lower than 20 V (see Figure 3).

Note 2: The same performance can be maintained at higher output levels if a bypassing capacitor is provited between pins 2 and 4.

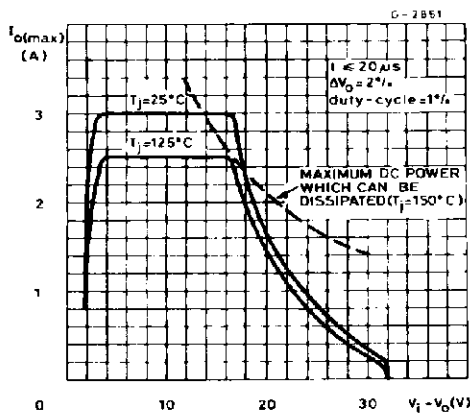### Figure 3. Typical Safe Operating Area Protection.

Figure 4. Quiescent Current vs. Supply Voltage.
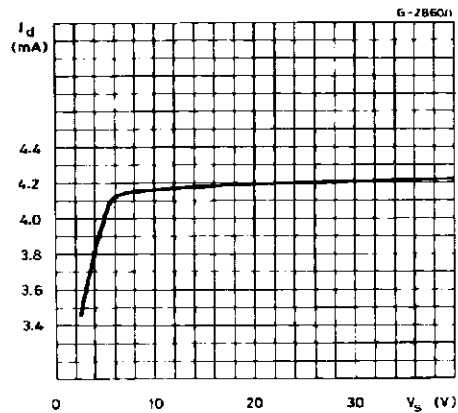
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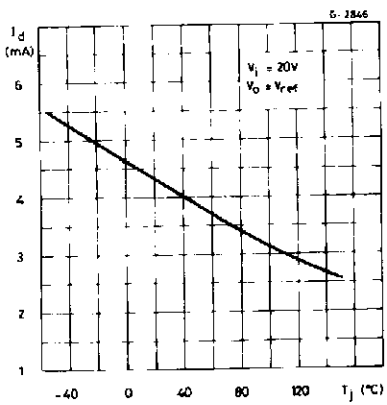**Figure 5. Quiescent Current vs. Junction Voltage.**

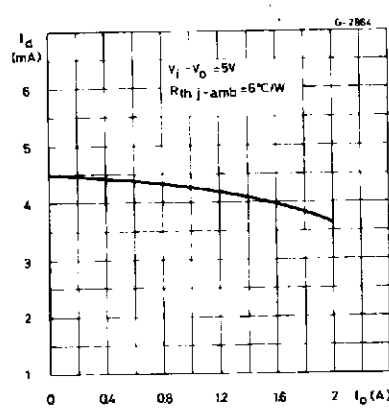**Figure 6. Quiescent Current vs. Output Current.**

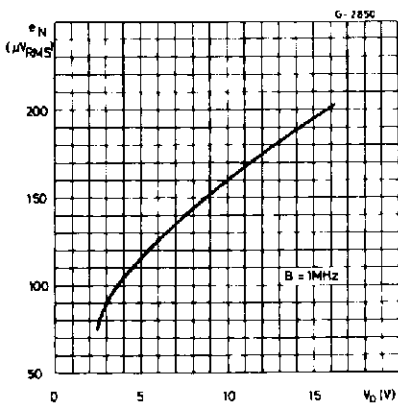**Figure 7. Output Noise Voltage vs. Output Voltage.**

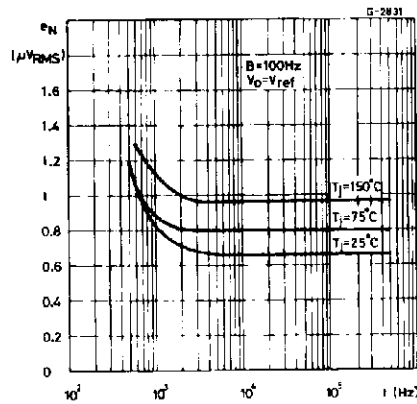**Figure 8. Output Noise Voltage vs. Frequency.**

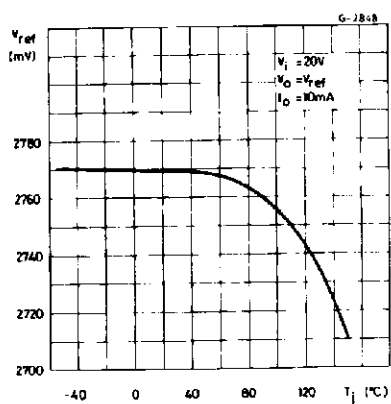**Figure 9. Reference Voltage vs. Junction Temperature.**

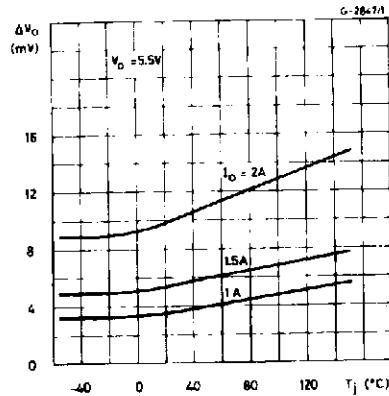
Figure 10. Voltage Load Regulation vs. Junction Temperature.
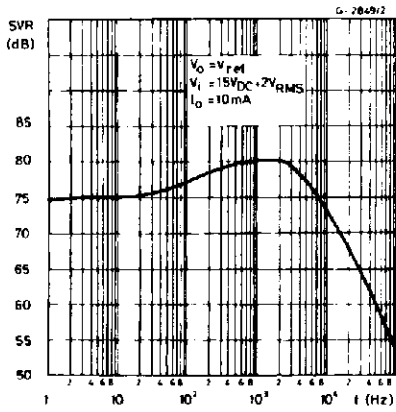
Figure 11. Supply Voltage Rejection vs. Frequency.
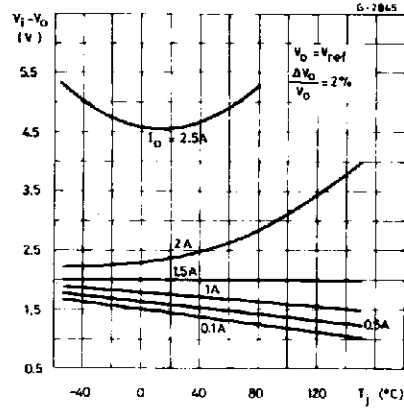

Figure 12. Dropout Voltage vs. Junction Temperature.

Figure 13. Output Impedance vs. Frequency.
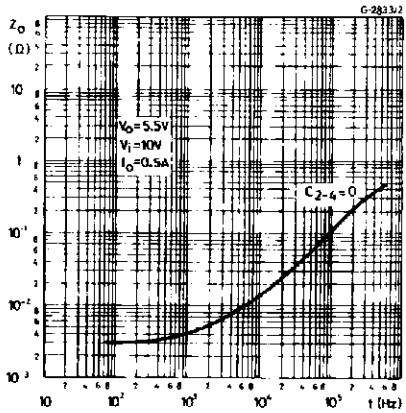
Figure 14. Output Impedance vs. Output Current.
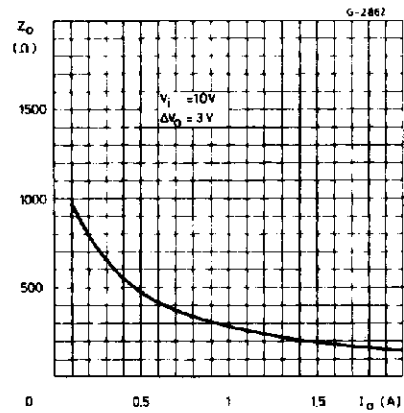
Figure 15. Voltage Transient Reponse.

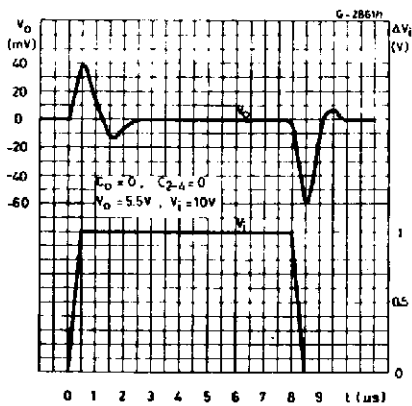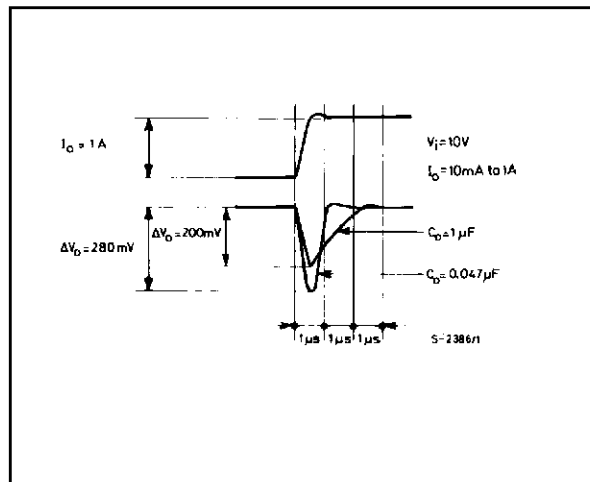**Figure 16. Load Transient Reponse.**

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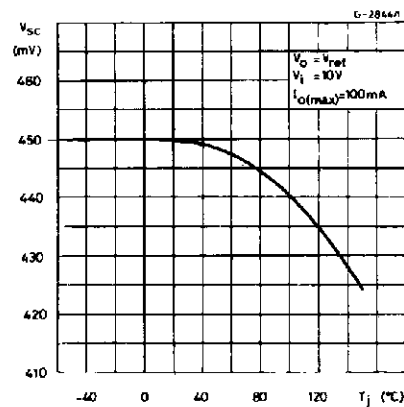**Figure 17. Load Transient Reponse**
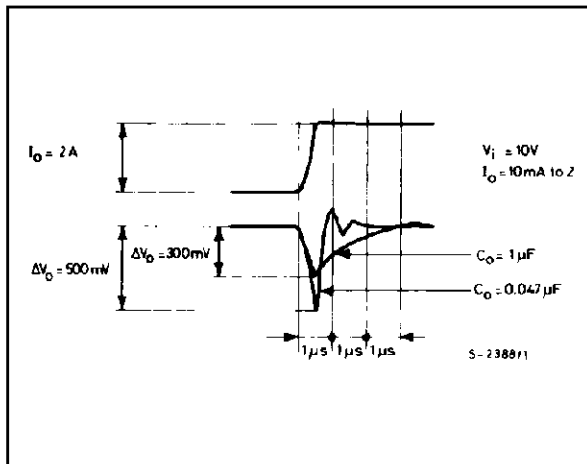
Figure 18. Current Limit Sense Voltage vs. Junction Temperature.

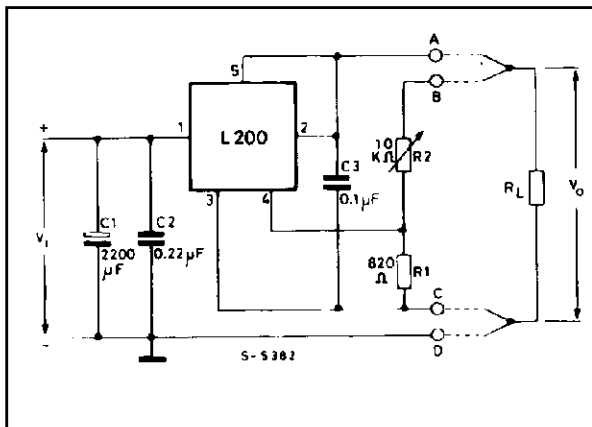## APPLICATIONS CIRCUITS

Figure 19. - Programmable Voltage Regulator

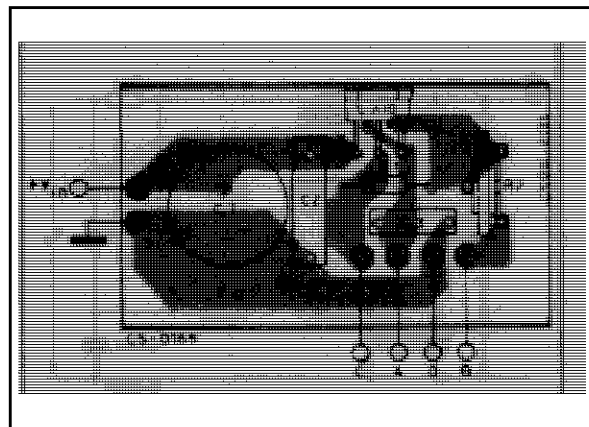**Figure 20. - P.C. Board and Components Layout of Figure 19.**

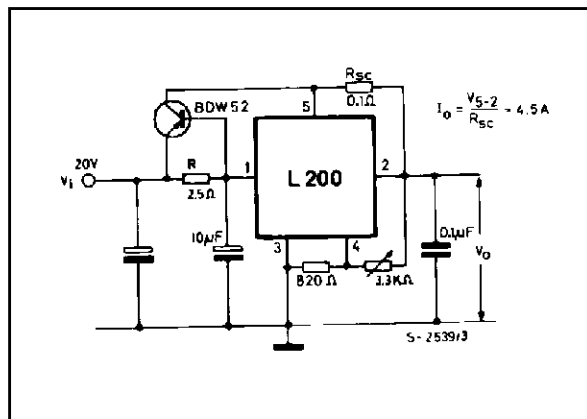**Figure 21. - High Current Voltage Regulator with Short Circuit Protection.**

$$I_O = \frac{V_{5-2}}{R_{sc}} = 4.5\,A$$

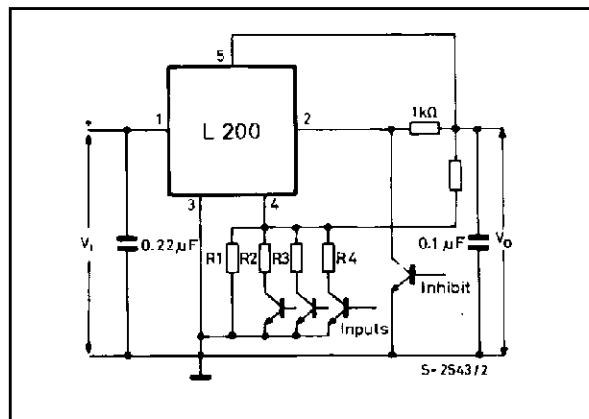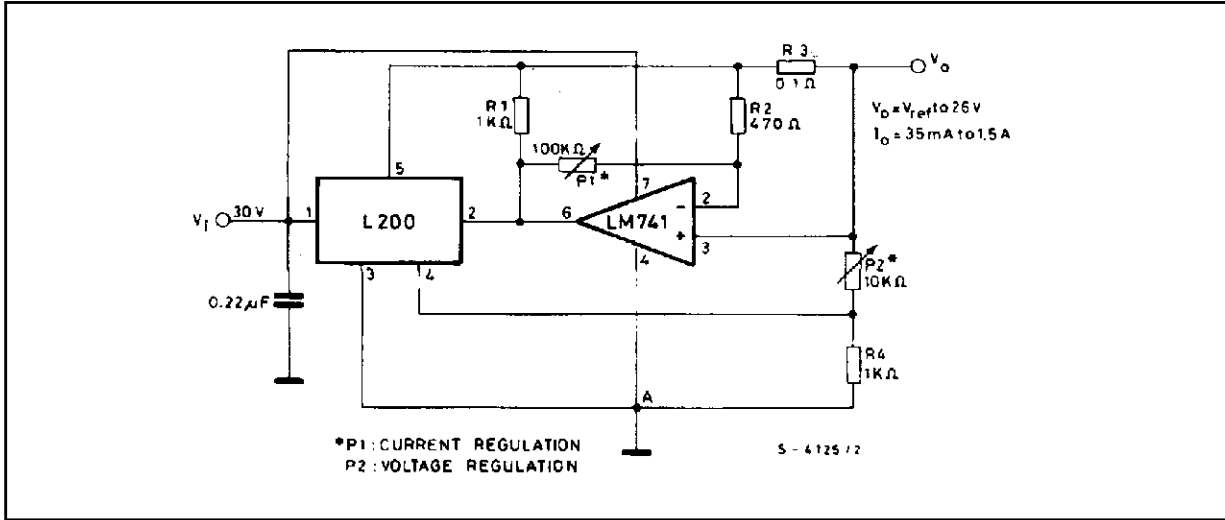**Figure 22. - Digitally Selected Regulator with Inhibit.**

Figure 23. Programmable Voltage and Current Regulator.

Note: Connecting point A to a negative voltage (for example - 3V/10 mA) it is possible to extend the output voltage
range down to 0 V and obtain the current limiting down to this level (output short-circuit condition).

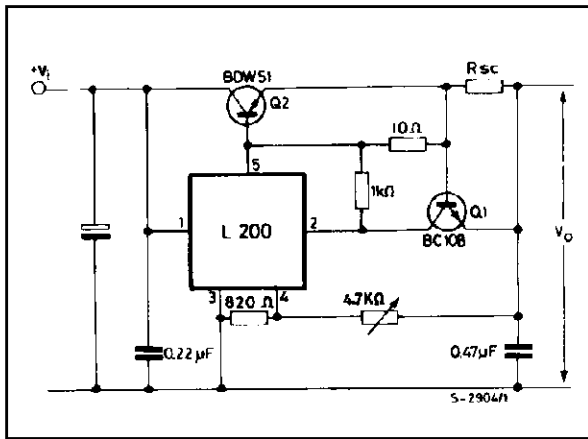**Figure 24. High Current Regulator with NPN Pass Transistor.**
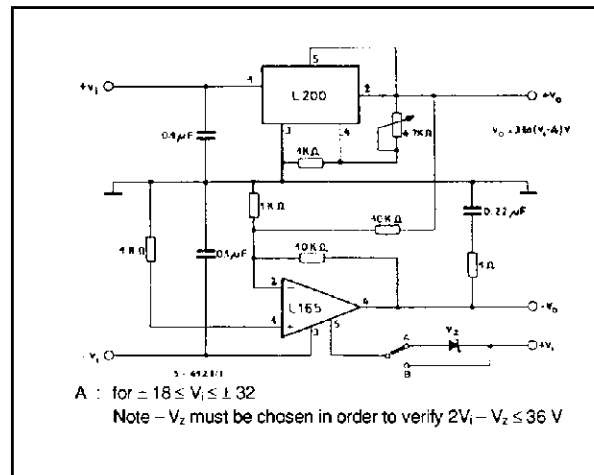

Figure 25. High Current Tracking Regualtor.

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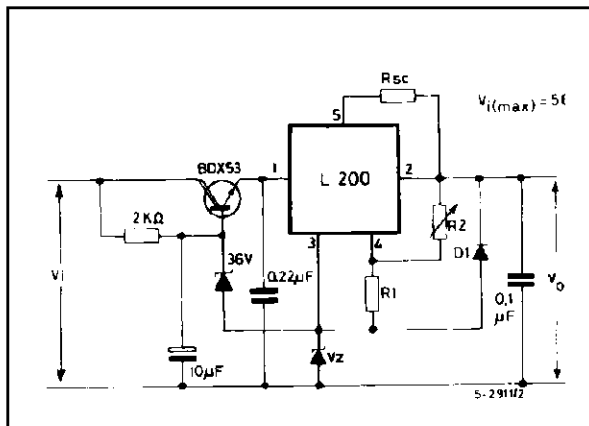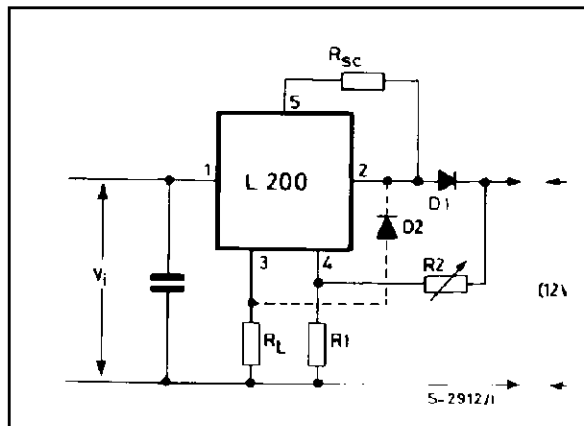
Figure 26. High Input and Output Voltage.

Figure 27. Constant Current Battery Charger.

The resistors R_1 and R_2 determine the final charging voltage and R_{SC} the initial charging current. D_1 prevents discharge of the battery throught the regulator.

The resistor RL limits the reverse currents through ther regulator (which should be 100 mA max) when the battery is accidentally reverse connected. If R_L is in series with a bulb of 12 V/50 mA rating this will indicate incorrect connection.
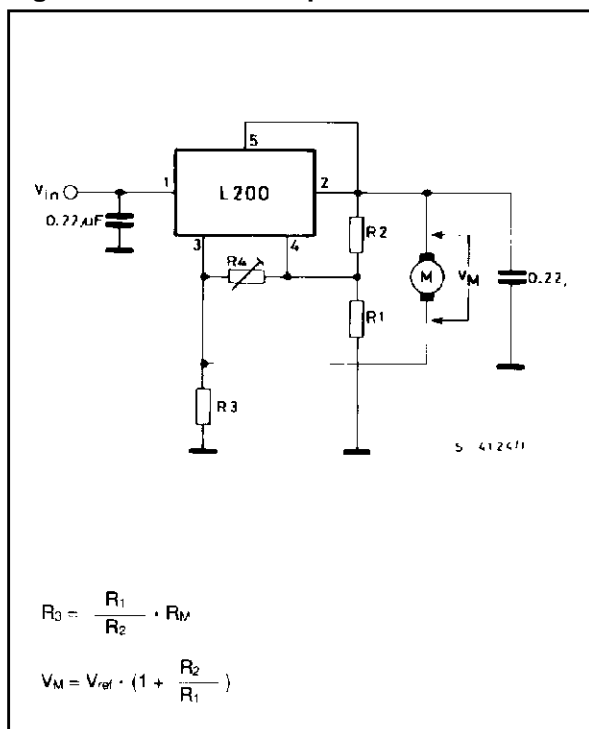
Figure 28. 30 W Motor Speed Control.

$$R_3 = \frac{R_1}{R_2} \cdot R_M$$

$$V_M = V_{ref} \cdot \left(1 + \frac{R_2}{R_1}\right)$$

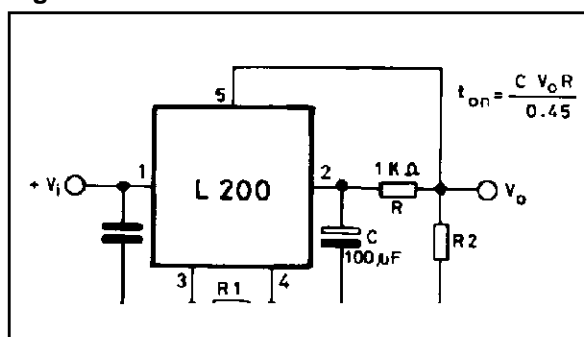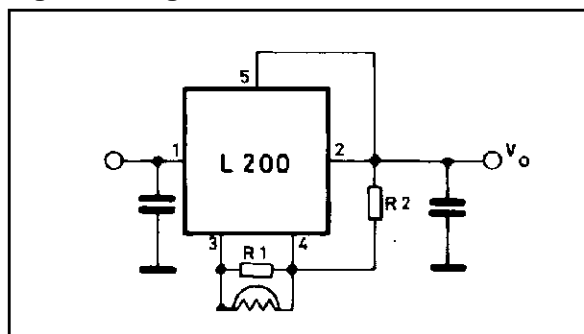## Figure 29. Loww Turn on.

$$t_{on} = \frac{C \, V_o \, R}{0.45}$$
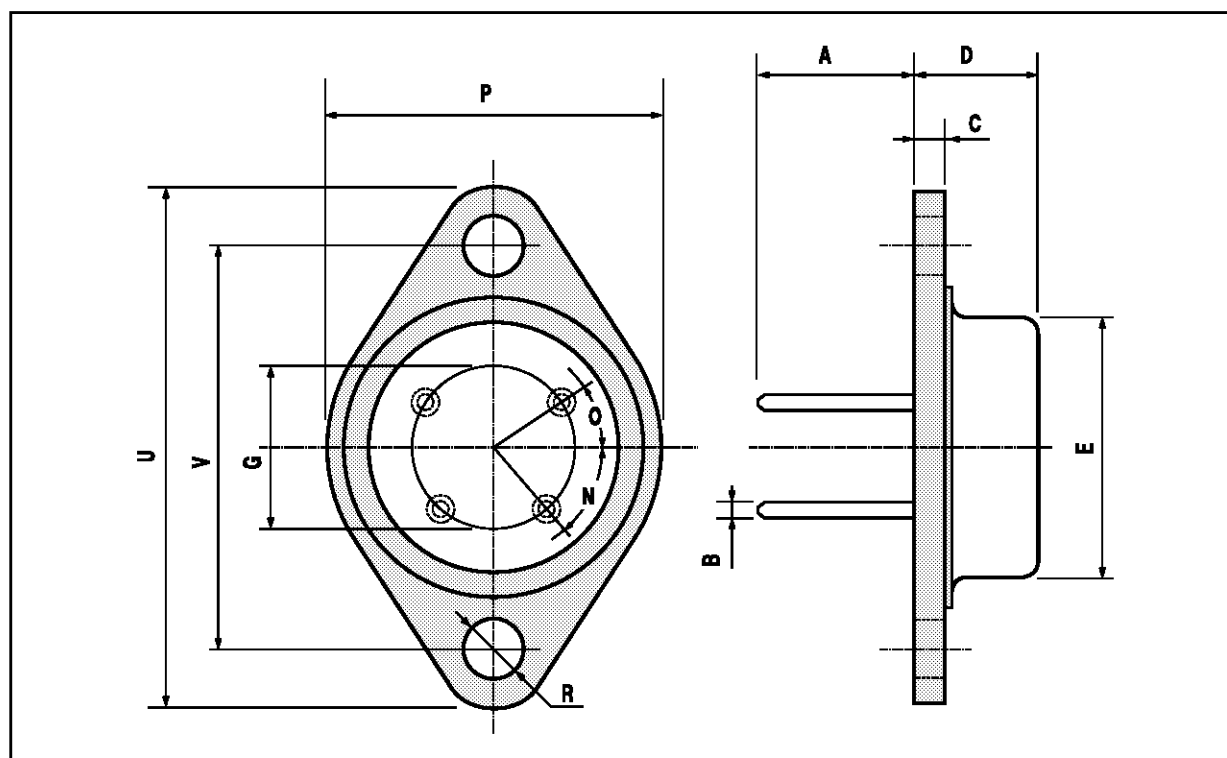
Figure 30. Light Controller.

PENTAWATT PACKAGE MECHANICAL DATA

DIM.	mm			inch		
	MIN.	**TYP.**	**MAX.**	**MIN.**	**TYP.**	**MAX.**
A			4.8			0.189
C			1.37			0.054
D	2.4		2.8	0.094		0.110
D1	1.2		1.35	0.047		0.053
E	0.35		0.55	0.014		0.022
F	0.8		1.05	0.031		0.041
F1	1		1.4	0.039		0.055
G		3.4		0.126	0.134	0.142
G1		6.8		0.260	0.268	0.276
H2			10.4			0.409
H3	10.05		10.4	0.396		0.409
L		17.85			0.703	
L1		15.75			0.620	
L2		21.4			0.843	
L3		22.5			0.886	
L5	2.6		3	0.102		0.118
L6	15.1		15.8	0.594		0.622
L7	6		6.6	0.236		0.260
M		4.5			0.177	
M1		4			0.157	
Dia	3.65		3.85	0.144		0.152

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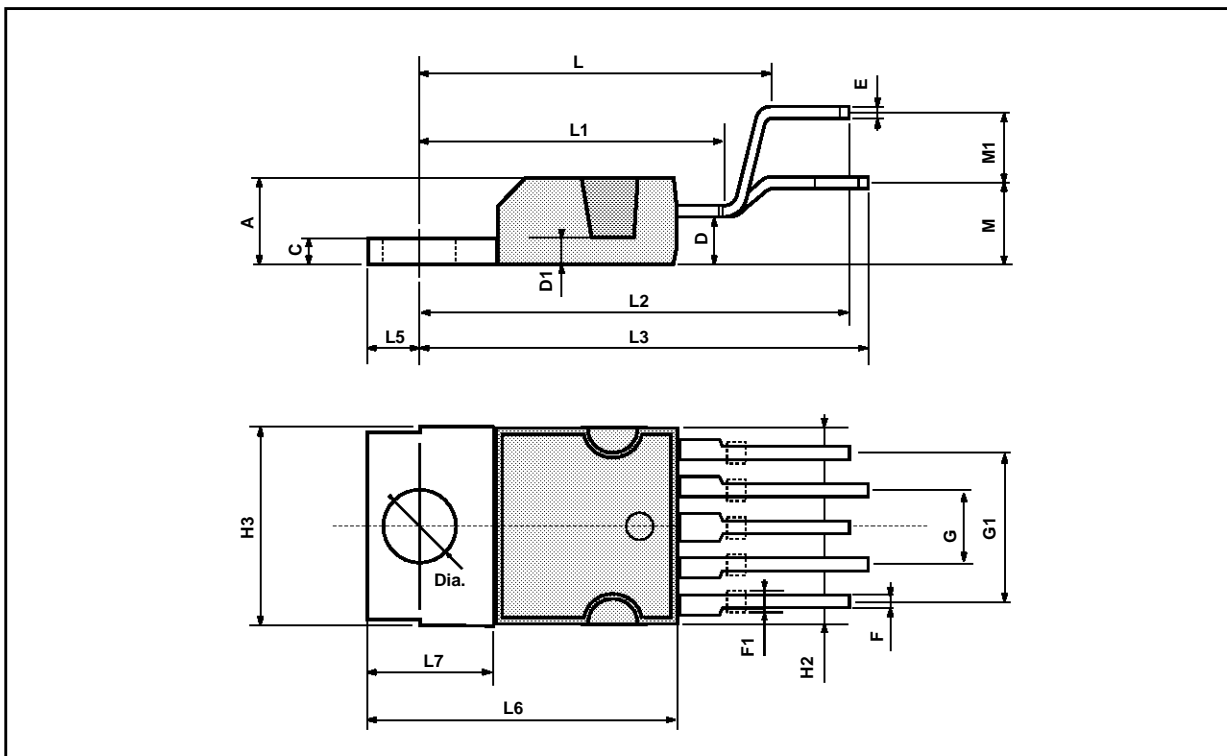
TO3 (4 LEAD) PACKAGE MECHANICAL DATA

DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A		11.8			0.46	
B (*)		1			0.39	
C			2.5			0.098
D			9.6			0.37
E			20			0.78
G		12.7			0.50	
N	50° (typ.)					
O	30° (typ.)					
P			26.2			1.03
R	3.88		4.20	0.15		0.16
U			39.5			1.55
V		30.1			1.18	

(*) Measured with Gauge

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